CSP16C04/CSB16C04



PRELIMINARY

16 AMPS, SCHOTTKY BARRIER RECTIFIERS

FEATURES

- Metal of silicon rectifier, major carrier conduction
- Low power loss, high efficient
- High current capability, low V_F







MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Tc=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Maximum Recurrent Peak Voltage	VRRM	40	V
Maximum RMS Voltage	VRMS	28	W.W.
Maximum DC Blocking Voltage	VDC	40	V
Maximum Average Forward Rectified Current at Tc=95°C	I F(AV)	16	A
Peak Forward SurgeCurrent, 8.3ms single half sine- wave superimposed on rated load (JEDEC Method)	I FSM	250	А
Maximum Forward Voltage a IF=8A, Tc=25°C	VF	0.62	V
Maximum Reverse Current at Peak Reverse Voltage ^a	lR	0.5	mA
Typical Thermal Resistance, Junction-to-Case	$R\theta JC$	3	°C/W
Typical Junction Capacitance, VR=4V	CJ	700	pF, g.G
Maximum Operating Junction Temperature	TJ	-65 to 125	°C
Maximum Storage Temperature	Тѕтс	-65 to 150	°C

NOTEE:a. Test Pulse Width 300us, Duty Cyale 2%

The information in this guide has been carefully checked and is believed to be reliable. However no responsibility can be assumed for inaccuracies that may not have been caught. All information in this guide is subject to change without prior notice. Furthermore CET cannot assume responsibility for the use of any license under the patent right of CET or any third parties. CET products are not authorized for use as critical components in life support devices or systems without express written approval of CET.



12

CSP16C04/CSB16C04

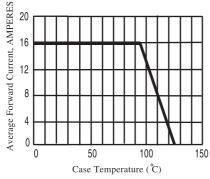


Figure 1. Forward Current Derating Curve

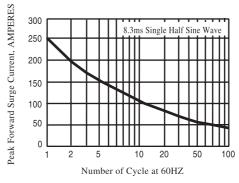
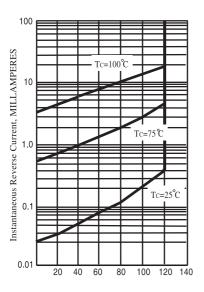
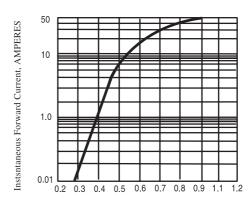


Figure 3. Maximum Non-Repetitive Surge Current



Percent of Rated Voltage Peak Reverse Voltage

Figure 2. Typical Reverse Characteristics



Instantaneous Forward Voltage (V)

Figure 4. Typical Instantaneous Forward Characteristics

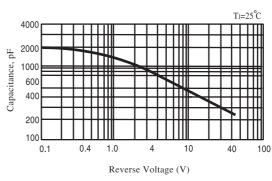


Figure 5. Typical Junction Capacitance